

Power Transistor (80V, 1A)

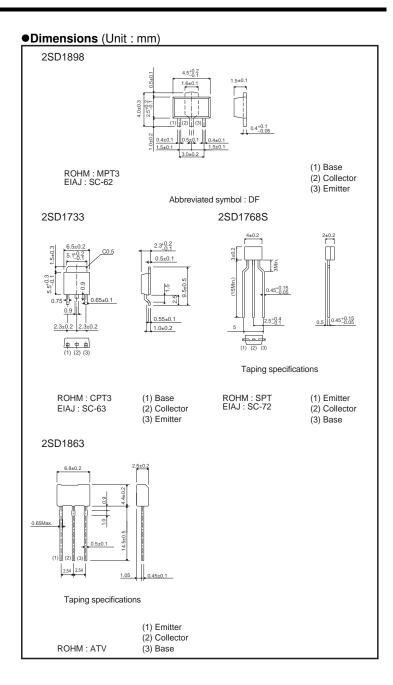
2SD1898 / 2SD1733 / 2SD1768S / 2SD1863

Features

- 1) High VCEO, VCEO=80V
- 2) High Ic, Ic=1A (DC)
- 3) Good hFE linearity
- 4) Low VCE (sat)
- 5) Complements the 2SB1260 / 2SB1241 / 2SB1181

Structure

Epitaxial planer type NPN silicon transistor



•Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		Vсво	120	V
Collector-emitter	voltage	Vceo	80	V
Emitter-base voltage		Vebo	5	V
		. 1 A		A (DC)
Collector current		lc	2	A (Pulse) *1
	2SD1898		0.5	W
			2	W *3
Collector power dissipation	2SD1733		1	W
		Pc	10	W (Tc=25°C)
	2SD1768S		0.3	W
	2SD1863		1	W *2
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

*1 Pw=20ms, duty=1 / 2
*2 Printed circuit board 1.7mm thick, collector copper plating 1cm² or larger.
*3 When mounted on a 40×40×0.7mm ceramic board.

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	120	-	-	V	Ic=50μA	
Collector-emitter breakdown voltage		BV _{CEO}	80	-	_	V	Ic=1mA	
Emitter-base breakdown voltage		BV _{EBO}	5	-	-	V	Ιε=50μΑ	
Collector cutoff current		Ісво	_	-	1	μΑ	Vcb=100V	
Emitter cutoff current		Іево	-	-	1	μΑ	VEB=4V	
	2SD1863	hfe *	120	-	390	_		
	2SD1733, 2SD1898		120	-	390	_	Vce=3V, Ic=0.5A	
	2SD1768S		120	-	390	_		
Collector-emitter saturation voltage		VCE(sat)	-	0.15	0.4	V	Ic/I _B =500mA/20mA	
Transition frequency		f⊤	_	100	_	MHz	Vce=10V, Ie=-50mA, f=100MHz	
Output capacitance		Cob	_	20	_	pF	Vcb=10V, Ie=0A, f=1MHz	

•Electrical characteristics (Ta=25°C)

* Measured using pulse current

Packaging specifications and hre

		Package		Та	oing	
		Code	T100	TL	TP	TV2
Туре	hfe	Basic ordering unit (pieces)	1000	2500	5000	2500
2SD1898	QR		0	-	-	-
2SD1733	QR		-	0	-	-
2SD1768S	QR		_	_	0	_
2SD1863	QR		_	_	_	0

hFE values are classified as follows :

Item	Q	R		
hfe	120 to 270	180 to 390		

Electrical characteristic curves 1000 Ta=25°C VCE=5V COLLECTOR CURRENT : Ic (mA) 0.1 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 BASE TO EMITTER VOLTAGE : VBE (V) Fig.1 Grounded emitter propagation characteristics COLLECTOR SATURATION VOLTAGE : VCE(sai) (V) 2.0 1.0 0.5 0.2 20/1 0. 0.05 0.02 0.01 100 1000 COLLECTOR CURRENT : Ic (mA) Fig.4 Collector-emitter saturation voltage vs. collector current 10 Ta=25°C Single non-repetitive Ic (A) nulse 500n COLLECTOR CURRENT 200n 100n 50n 20n 10r 5n 2n 1m .10.2 0.5 1 2 5 10 20 501002005001000



Fig.7 Safe operating area (2SD1863)

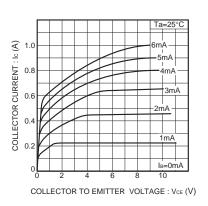


Fig.2 Grounded emitter output characteristics

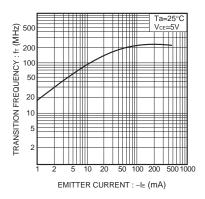


Fig.5 Gain bandwidth product vs. emitter current

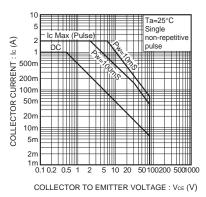
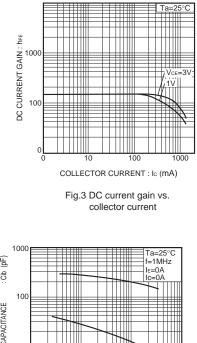
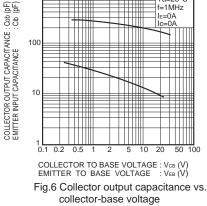


Fig.8 Safe operating area (2SD1898)





Emitter input capacitance vs. emitter-base voltage

	Notes
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